TOSHIBA Bipolar Digital Integrated Circuit Silicon Monolithic

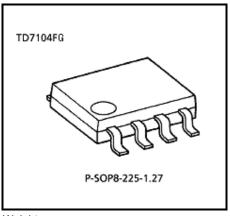
# **TD7104FG**

#### ECL Prescaler for Digital Synthesized Tuner

The TD7104FG is a general-purpose fixed dividing prescaler developed for digital tuning system of the PLL frequency synthesizer type, and can operate at up to 1 GHz.

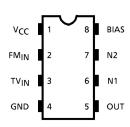
#### **Features**

- Maximum operating frequency 1 GHz (at 1 / 8 dividing mode)
- Dividing ratios of 1 / 8, 1 / 4, and 1 / 2 are available.
- Independent TV and FM inputs are provided.
   In FM mode, this IC can function as a buffer amplifier (1/1 dividing).
- The built in input amplifier contributes to realizing high input voltage sensitivity.
- Built in standby circuit

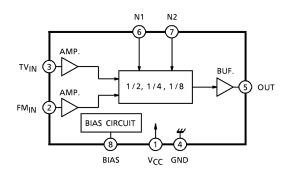


Weight P-SOP8- 225-1.27 : 76 mg (typ.)

#### **Pin Connection**



#### **Block Diagram**





## **Pin Function**

Pin No.	Symbol	Pin Name	Function And Description	Remarks	
1	$V_{CC}$	Power supply terminal	Applies voltage of V <sub>CC</sub> = 3.0 to 5.5V	_	
2	FM <sub>IN</sub>	FM local OSC. signal input terminal	Inputs local oscillation signal in FM band. $f_{\rm IN}$ = 50 to 200MHz, FM $_{\rm IN}$ input signal is output by a 1 / 1 dividing ratio (buffer amplifier).	Built–in input Amp. provided	
3	$TV_IN$	TV local OSC. signal input terminal	Inputs local oscillation signal in TV band. F <sub>IN</sub> = 50M to 1.0GHz, TV <sub>IN</sub> input signal is output by a 1 / 8, 1 / 4, or 1 / 2 dividing ratio, which is controlled through N1 and N2 input.	Built–in input Amp. provided	
4	GND	Ground terminal	Grounds.	_	
5	Out	Dividing signal output terminal	Outputs dividing signal.	_	
6	N1	Dividing ratio selecting	These inputs control the selection of a dividing ratio among 1 / 1, 1 / 2, 1 / 4, and 1 / 8.	_	
7	N2	control terminal	FM <sub>IN</sub> terminal is selected at N1 = N2 = "L" level (1 / 1 dividing). The truth table is shown below.		
8	BIAS	BIAS terminal	Connects capacitors on bias circuit. Change this pin to low to convert the IC is to stand-by mode.	_	

## **Truth Table**

Receiving Band	Input Terminal	Operating Frequency Range	Dividing Ratio	N1	N2
FM	FM <sub>IN</sub>	50M~200MHz	÷1	0	0
TV		50M~400MHz	÷2	1	0
	TV <sub>IN</sub>	100M~500MHz	÷4	0	1
		100M~1.0GHz	÷8	1	1

## **Maximum Ratings (Ta = 25°C)**

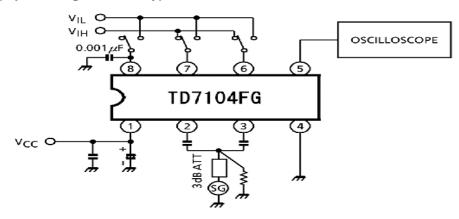
Characteristic	Symbol	Rating	Unit	
Power supply voltage	V <sub>CC</sub>	6.5	V	
Power dissipation	P <sub>D</sub>	450 (200) (*)	mW	
Input voltage	V <sub>in</sub>	-0.3~V <sub>CC</sub> + 0.3	V	
Operating temperature	T <sub>opr</sub>	-30~75	°C	
Storage temperature	T <sub>stg</sub>	-55~150	°C	

<sup>(\*)</sup> Flat package

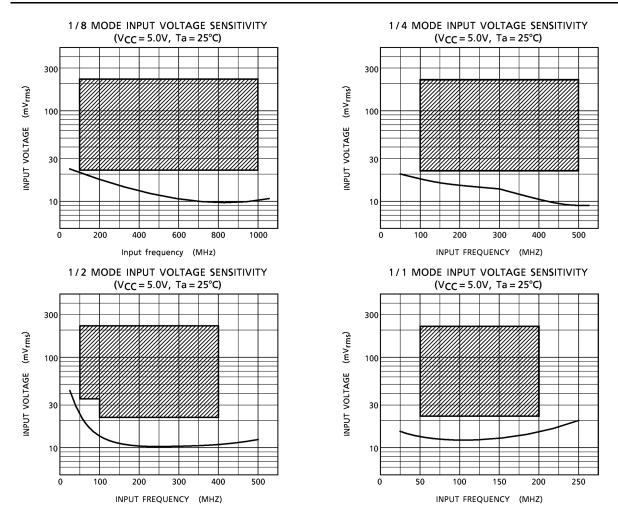
#### Electrical Characteristics (unless otherwise specified, $V_{CC} = 3.0 \sim 6.0 \text{V}$ , Ta = $-30 \sim 75 ^{\circ}\text{C}$ )

Charact	eristic	Symbol	Test Cir cuit	Test Condition		Min.	Тур.	Max.	Unit
Power supply vo	oltage	V <sub>CC</sub>	_	_		3.0	~	6.0	V
Operating supply current		I <sub>CC1</sub>	_	V <sub>CC</sub> = 5.0V, ÷8, ÷4		_	14	20	mA
		I <sub>CC2</sub>	_	V <sub>CC</sub> = 5.0V, ÷2		_	11	18	
		I <sub>CC3</sub>	_	V <sub>CC</sub> = 5.0V, FM mode		_	7	13	
Stand-by current		I <sub>CS</sub>	_	V <sub>CC</sub> = 5.0V, BIAS = GND		_	30	70	μA
		f <sub>IN1</sub>		÷8, TV <sub>IN</sub>		100	_	1000	
Operating frequ	ency	f <sub>IN2</sub>	1	÷4, TV <sub>IN</sub>		100	_	500	MHz
range		f <sub>IN3</sub>		÷2, TV <sub>IN</sub>		50	_	400	IVITZ
		f <sub>IN4</sub>		FM mode, FM <sub>IN</sub>		50	_	200	]
		V <sub>IN1</sub>		TV <sub>IN</sub> (÷8, ÷4)		22.0	_	220	
Innut voltage re	222	V	1	T\( (:2)	f <sub>IN</sub> = 50~100MHz	35.0	_	220	m\/
Input voltage range		V <sub>IN2</sub>	ı	1 $ TV_{IN}(\div 2) $ $ f_{IN} = 100 \sim 40$	f <sub>IN</sub> = 100~400MHz	22.0	_	220	- mV <sub>rms</sub>
		V <sub>IN3</sub>		FMIN		22.0	_	220	
Output amplitude		V <sub>OUT</sub>	1	Out, C <sub>L</sub> = 3pF		0.4	0.5	_	V <sub>p-p</sub>
Input voltage	"H" level	V <sub>IH</sub>	_	N1, N2, BIAS		2.5	_	V <sub>CC</sub>	V
	"L" level	V <sub>IL</sub>		N1, N2, BIAS		0	_	8.0	l v
Input ourront	"H" level	lін	_	N1, N2, BIAS, V <sub>CC</sub> = 5.0V V <sub>IH</sub> = 4.0V		_	_	100	- μΑ
Input current	"L" level	I <sub>ΙL</sub>	I	N1, N2, BIAS, V <sub>CC</sub> = 5.0V V <sub>IL</sub> = 1.0V		ı	_	10	

# Test Circuit 1 (input voltage sensitivity)

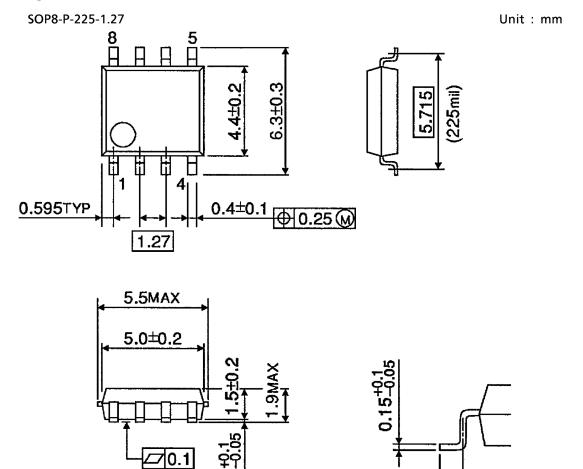


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(Note) Operating range ( $V_{CC} = 3.0 \sim 6.0 \text{V}$ ,  $T_a = -30 \sim 75 ^{\circ}\text{C}$ )

## **Package Dimensions**



Weight: 76 mg (typ.)

0.525±0.2

Regarding solderability, the following conditions have been confirmed:

- Solderability
  - (1) Use of Sn-63Pb solder bath
    - solder bath temperature = 230°C
    - · dipping time = 5 seconds
    - · the number of times = once
    - · use of R-type flux
  - (2) Use of Sn-3.0Ag-0.5Cu solder bath
    - · solder bath temperature = 245°C
    - · dipping time = 5 seconds
    - · the number of times = once
    - · use of R-type flux

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